# HER3001PT - HER3006PT



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# **30A, 50V - 600V High Efficient Rectifier**

### FEATURES

- AEC-Q101 qualified available
- Low forward voltage, high current capability
- Low thermal resistance
- Low power loss, high efficiency
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

### APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Lighting application
- Snubber
- Freewheeling application

### **MECHANICAL DATA**

- Case: TO-247AD (TO-3P)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Mounting torque: 1.13 N⋅m maximum
- Polarity: As marked
- Weight: 5.60g (approximately)

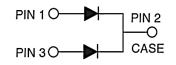
KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
١ <sub>F</sub>	30	А		
V <sub>RRM</sub>	50 - 600	V		
I <sub>FSM</sub>	300	А		
T <sub>J MAX</sub>	150	°C		
Package	TO-247AD	(TO-3P)		
Configuration	Dual dies			





TO-247AD (TO-3P)

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ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)								
		HER	HER	HER	HER	HER	HER	
PARAMETER	SYMBOL	3001	3002	3003	3004	3005	3006	UNIT
		PT	PT	PT	PT	PT	РТ	
		HER	HER	HER	HER	HER	HER	
Marking code on the device		3001	3002	3003	3004	3005	3006	
		PT	PT	PT	PT	PT	PT	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	210	280	420	V
Forward current	I <sub>F</sub>			3	0			А
Surge peak forward current 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	300		А				
Junction temperature	TJ	-55 to +150		°C				
Storage temperature	T <sub>STG</sub>			-55 to	+150			°C



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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R <sub>eJC</sub>	1.4	°C/W

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	МАХ	UNIT
Forward voltage per diode <sup>(1)</sup>	HER3001PT HER3002PT HER3003PT HER3004PT		V <sub>F</sub>	-	1.0	V
	HER3005PT	······································		-	1.3	V
	HER3006PT			-	1.7	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>		T <sub>J</sub> = 25°C	- I <sub>R</sub>	-	10	μA
		T <sub>J</sub> = 125°C		-	500	μA
Junction capacitance per diode	HER3001PT HER3002PT HER3003PT HER3004PT HER3005PT	1MHz, V <sub>R</sub> = 4.0V	CJ	175	-	pF
	HER3006PT			145	-	pF
Reverse recovery time	erse recovery time HER3002PT HER3003PT HER3004PT HER3005PT		t <sub>rr</sub>	-	50	ns
	HER3006PT			-	80	ns

### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE <sup>(1)(2)</sup>	PACKAGE	PACKING
HER30xPT	TO-247AD (TO-3P)	30 / Tube
HER30xPTH	TO-247AD (TO-3P)	30 / Tube

### Notes:

- 1. "x" defines voltage from 50V(HER3001PT) to 600V(HER3006PT)
- 2. "H" means AEC-Q101 qualified



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### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

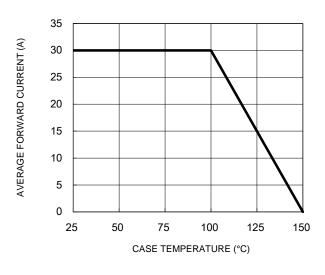
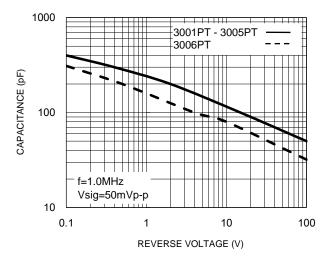
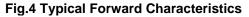


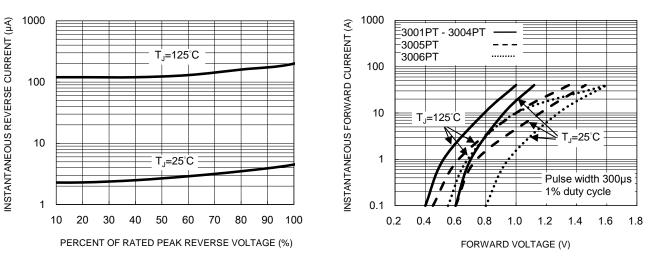
Fig.1 Forward Current Derating Curve

### **Fig.3 Typical Reverse Characteristics**



### **Fig.2 Typical Junction Capacitance**





# $10^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{0}^{10}_{10}^$

### Fig.5 Maximum Non-Repetitive Forward Surge Current



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### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

### 50Ω 10Ω - trr 🗕 NONINDUCTIVE NONINDUCTIVE ~~~ ~~~ +0.5A (-) ± DUT • (+) 50Vdc PULSE 0 GENERATOR = (approx) -0.25A (NOTE 2) (-) IΩ OSCILLOSCOPE 6 (+) (NOTE 1) -1.0A NOTES: 1. Rise Time=7ns max. Input Impedance= ≐ 1 megohm 22pf 2. Rise Time=10ns max. Sourse Impedance= 50 ohms

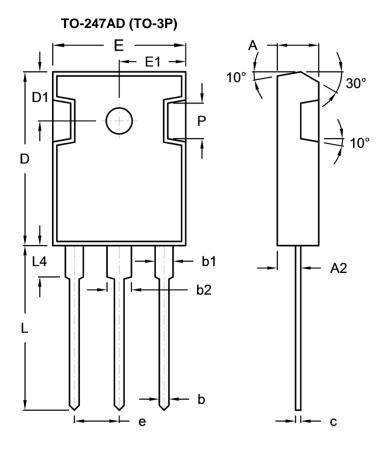
### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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## PACKAGE OUTLINE DIMENSIONS



DIM	Unit (mm)		Unit	(inch)	
	Min	Max	Min	Max	
А	4.90	5.16	0.193	0.203	
A2	2.70	3.00	0.106	0.118	
b	1.12	1.22	0.044	0.048	
b1	1.93	2.18	0.076	0.086	
b2	2.97	3.22	0.117	0.127	
с	0.51	0.76	0.020	0.030	
D	20.80	21.30	0.819	0.839	
D1	5.70	6.20	0.224	0.244	
E	15.90	16.40	0.626	0.646	
E1	7.90	8.20	0.311	0.323	
е	5.20	5.70	0.205	0.224	
н	2.90	3.40	0.114	0.134	
L	19.70	20.20	0.776	0.795	
L4	3.50	4.10	0.138	0.161	
Р	-	4.30	-	0.169	

### **MARKING DIAGRAM**



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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